## MSKSEMI















**ESD** 

TVS

TSS

MOV

GDT

**PLED** 

# Broduct data sheet



SMA

#### **FEATURES**

- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Fast switching for high efficiency
- Low reverse leakage
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 250°C/10 seconds at terminals

#### **MECHANICAL DATA**

Case: JEDEC DO-214AC molded plastic body

Terminals: Solder plated, solderable per MIL-STD-750,

Method 2026

Polarity: Color band denotes cathode end Mounting Position: Any Weight: 0.003 ounce, 0.093 grams

0.004 ounce, 0.111 grams SMA(H)

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified. Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

Characteristic	SYMBOLS	RS1A	RS1B	RS1D	RS1G	RS1J	RS1K	RS1M	UNITS
Maximum repetitive peak reverse voltage		50	100	200	400	600	800	1000	V
Maximum RMS voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at TL=90°C	l <sub>(AV)</sub>			•	1.0				Α
Peak forward surge current									
8.3ms single half sine-wave superimposed on		30.0				Α			
rated load (JEDEC Method)									
Maximum instantaneous forward voltage at 1.0A	V <sub>F</sub>				1.3				V
Maximum DC reverse current Ta=25°C	5.0								
at rated DC blocking voltage T <sub>A</sub> =100°C	l <sub>R</sub>	50.0					μA		
Maximum reverse recovery time (NOTE 1)	trr		15	0		250	50	00	ns
Typical junction capacitance (NOTE 2)	Сл				15.0				pF
Typical thermal resistance (NOTE 3)	Reja				50.0				°C/W
Operating junction and storage temperature range		-65 to +150			°C				

Note:1.Reverse recovery condition IF=0.5A,IR=1.0A,Irr=0.25A 2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

3.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas







AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE 1.0 8.0 0.6 Single Phase Half Wave 60Hz Resistive or inductive Load 0.4 0.2 0 25 75 50 100 125 150 175 AMBIENT TEMPERATURE,°C

PEAK FORWARD SURGE CURRENT, AMPERES

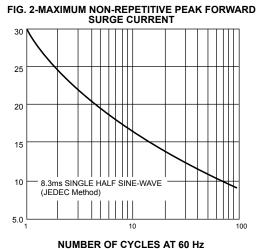


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

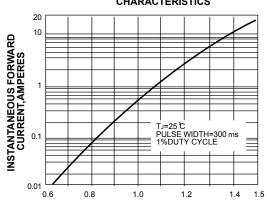
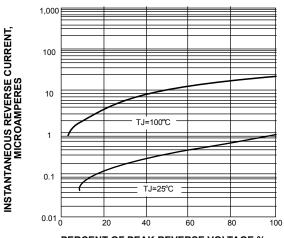
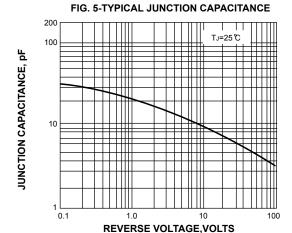


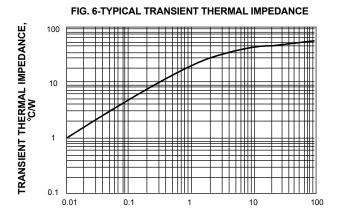
FIG. 4-TYPICAL REVERSE CHARACTERISTICS



INSTANTANEOUS FORWARD VOLEAGE, VOLTS



PERCENT OF PEAK REVERSE VOLTAGE,%

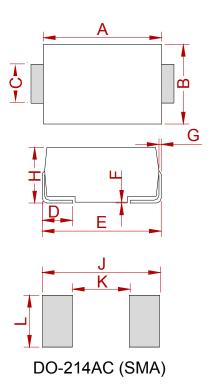


t,PULSE DURATION,sec.





## **PACKAGE MECHANICAL DATA**



		Dimensions						
Ref.	Millir	neters	Inches					
	Min.	Max.	Min.	Max.				
Α	4.25	4.65	0.167	0.183				
В	2.50	2.90	0.098	0.114				
С	1.35	1.65	0.053	0.065				
D	0.76	1.52	0.030	0.060				
Е	4.93	5.28	0.194	0.208				
F	0.051	0.203	0.002	0.008				
G	0.15	0.31	0.006	0.012				
Н	1.98	2.41	0.078	0.095				
J	6.50		0.256					
K		2.30		0.090				
L	1.70		0.067					

## **REEL SPECIFICATION**

P/N	PKG	QTY
RS1A THRU RS1M	SMA	2000



### Attention

- Any and all MSKSEMI Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your MSKSEMI Semiconductor representative nearest you before using any MSKSEMI Semiconductor products described or contained herein in such applications.
- MSKSEMI Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specificationsof any andall MSKSEMI Semiconductor products described orcontained herein.
- Specifications of any and all MSKSEMI Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- MSKSEMI Semiconductor. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with someprobability. It is possiblethat these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits anderror prevention circuitsfor safedesign, redundant design, and structural design.
- In the event that any or all MSKSEMI Semiconductor products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from theauthorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of MSKSEMI Semiconductor.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. MSKSEMI Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringementsof intellectual property rights or other rightsof third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. Whendesigning equipment, referto the "Delivery Specification" for the MSKSEMI Semiconductor productthat you intend to use.

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by MSKSEMI manufacturer:

Other Similar products are found below:

70HFR40 FR105 R0 RL252-TP 1N5397 JANTX1N5634A 1N4002G 1N4005-TR JANS1N6640US 481235F RRE02VS6SGTR 067907F MS306 US2JFL-TP A1N5404G-G CRS12(T5L,TEMQ) ACGRB207-HF CLH07(TE16L,Q) CLH03(TE16L,Q) ACGRC307-HF ACEFC304-HF DZ-1380 NTE6356 NTE6359 JAN1N5555 85HFR60 40HFR60 70HF120 85HFR80 D126A45C SCF7500 SCHJ22.5K SM100 SCPA2 SDHD5K ACGRA4001-HF D1821SH45T PR D1251S45T NTE6358 NTE5850 NTE5819 NTE5837 NTE5892 NTE5900 NTE5911 NTE5915 NTE5921 NTE6104 NTE6105 NTE6154 NTE6158